

Part Number

Customer

| Category      | Parameter                           | Specification                                                                         | Measurement Method                   |
|---------------|-------------------------------------|---------------------------------------------------------------------------------------|--------------------------------------|
| OverallWafer  | 1.0 Diameter                        | 150.00 +/- 0.20 mm                                                                    |                                      |
|               | 2.0 Primary Flat Orientation        | {110} +/- 0.5 degree                                                                  | Wafer Vendor                         |
|               | 3.0 Primary Flat Length             | 57.50 +/- 2.50 mm                                                                     | Wafer Vendor                         |
|               | 5.0 Overall Thickness               | 250.00 +/- 3.00 $\mu$ m                                                               | ADE, 100%                            |
|               | 6.0 Total Thickness Variation (TTV) | <2.00 $\mu$ m                                                                         | Guaranteed by Process                |
|               | 7.0 Bow                             | <40.00 $\mu$ m                                                                        | ADE to ASTM F534, 20%                |
|               | 8.0 Warp                            | <40.00 $\mu$ m                                                                        | ADE to ASTM F657, 20%                |
| HandleSilicon | 11.0 Handle Growth Method           | CZ                                                                                    | Wafer Vendor                         |
|               | 11.5 Handle Oxygen Concentration    | 13-17ppm                                                                              |                                      |
|               | 12.0 Handle Orientation             | {100} +/- 0.5 degree                                                                  | Wafer Vendor                         |
|               | 13.0 Handle Thickness               | 250.00 +/- 3.00 $\mu$ m                                                               | ADE, 100%                            |
|               | 14.0 Handle Doping Type             | N                                                                                     | Wafer Vendor                         |
|               | 15.0 Handle Dopant                  | Phosphorous                                                                           | Wafer Vendor                         |
|               | 16.0 Handle Resistivity             | 1-3 Ohmcm                                                                             | Wafer Vendor                         |
|               | 17.0 Backside Finish                | Polished with lasermarking - unique laser mark as per SEMI M12 (last 4 digits unique) | Wafer Vendor                         |
| DeviceSilicon | 18.0 LPD Count                      | <30.00pcs                                                                             | @0.3um, Tencor 6220 particle counter |
|               | 19.0 Scratches                      | 0                                                                                     | Bright Light, 100% (note 2)          |
|               | 20.0 Haze                           | none                                                                                  | Bright Light, 100% (note 2)          |

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|------------------|-------------------|-----------------------------------------------------------------------------------------|--|
| Shipping Details | Wafer per box :   | Max 25                                                                                  |  |
|                  | Packaging :       | Taped Polypropylene Wafer Box<br>Empak, Ultrapak, 150.00mm<br>Antistatic Double Bagging |  |
|                  | Lot Shipment Data | Device Thickness<br>Bow / Warp Data<br>Handle and SOI Thickness                         |  |



Explanatory Notes 1. Microscope inspection performed using microscope scan as below. 5x objective.

2. All bright light inspections performed exclude all wafer area outside the edge exclusion defined in Overall Wafer, Edge Exclusion. High intensity bright lamp inspection as per ASTM F523.

3. 9 point measurement are as shown in the diagram below:



Additional Information